NSN 5961-00-443-8553

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-443-8553 **Inclosure Material:** Glass **Overall Length:** Between 0.150 inches and 0.175 inches **Terminal Length:** 0.175 inches **Overall Diameter:** Between 0.065 inches and 0.075 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case and burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc **Power Rating Per Characteristic:** 313.0 milliwatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** Between 0.3 and 0.6 **Test Data Document:** 37695-619327 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: